Sensors

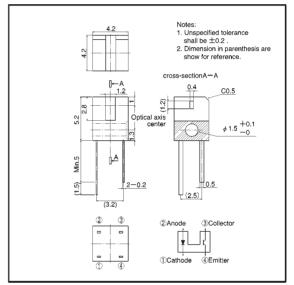
Photointerrupter, double-layer mold type RPI-131

The RPI-131 is an ultra-small size, doulble-layer photointerrupter.

Applications
Optical control equipment
Cameras
Floppy disk drives

Features

- 1) Ultra-small.
- 2) Minimal influence from stray light.
- 3) Low collector-emitter saturation voltage.



•Absolute maximum ratings (Ta = 25° C)

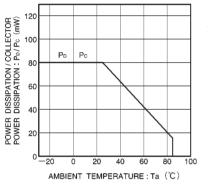
Parameter		Symbol	Limits	Unit
Input(LED)	Forward current	lf	50	mA
	Reverse voltage	VR	5	V
Inpl	Power dissipation	PD	80	mW
Output (photo- (transistor)	Collector-emitter voltage	VCEO	30	V
	Emitter-collector voltage	VECO	4.5	V
	Collector current	lc	30	mA
	Collector power dissipation	Pc	80	mW
Operating temperature		Topr	-25~+85	ĉ
Storage temperature		Tstg	-40~+100	ĉ

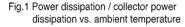
External dimensions (Units: mm)

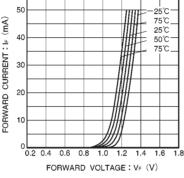
Parameter		Symbol	Min.	Тур.	Max.	Unit	Conditions
<u>۲</u>							
Input charac- teristics	Forward voltage	VF		1.3	1.6	V	IF=50mA
	Reverse current	IR	—	—	10	μA	V _R =5V
Output charac- teristics	Dark current	ICEO	—	—	0.5	μA	V _{CE} =10V
	Peak sensitivity wavelength	λp	—	800	—	nm	—
Transfer charac- teristics	Collector current	lc1	0.7	—	—	mA	Vce=5V, Ir=20mA
		Ic2	0.2	—	—	mA	Vc∈=5V, I⊧=5m
	Collector-emitter saturation voltage	VCE(sat)	_	_	0.3	v	I⊧=20mA, Ic=0.3mA
	Response time	tr∙tf	_	10	_	μs	Vcc=5V, I⊧=20mA, RL=100Ω

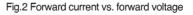
•Electrical and optical characteristics (Ta = 25° C)

Electrical and optical characteristic curves









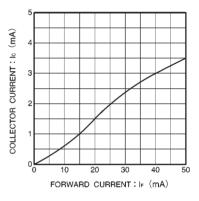


Fig.3 Collector current vs. forward current

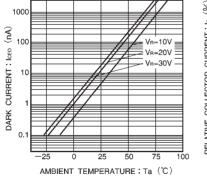


Fig.4 Dark current vs. ambient temperature

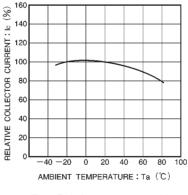


Fig.5 Relative output vs. ambient temperature

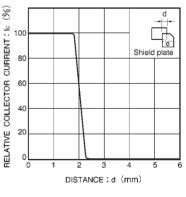
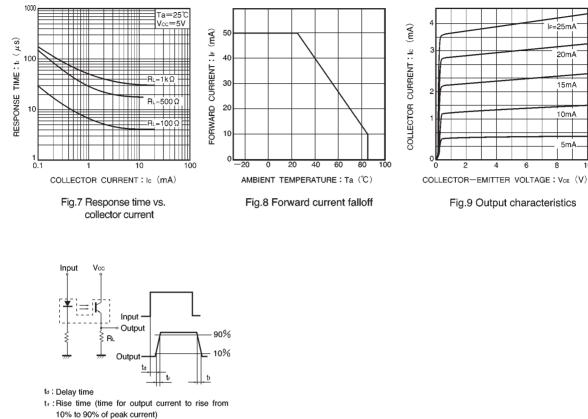


Fig.6 Relative output current vs. distance



10



tr : Fall time (time for output current to fall from 90% to 10% of peak current)

Fig.10 Response time measurement circuit

